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Intel - 5AGZME7K3F40C4N Datasheet



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Understanding <u>Embedded - FPGAs (Field</u> <u>Programmable Gate Array)</u>

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details

Details	
Product Status	Obsolete
Number of LABs/CLBs	21225
Number of Logic Elements/Cells	450000
Total RAM Bits	40249344
Number of I/O	674
Number of Gates	-
Voltage - Supply	0.82V ~ 0.88V
Mounting Type	Surface Mount
Operating Temperature	0°C ~ 85°C (TJ)
Package / Case	1517-BBGA, FCBGA
Supplier Device Package	1517-FBGA (40x40)
Purchase URL	https://www.e-xfl.com/product-detail/intel/5agzme7k3f40c4n

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

Transceiver Specifications for Arria V GT and ST Devices

Symbol/Description	Condition	Tran	sceiver Speed Gra	ide 3	Unit
Symbol/Description	Condition	Min	Тур	Max	Onic
Supported I/O standards	1.2 V PCML, 1.4 VPCML	1.5 V PCML, 2.5	V PCML, Differe	ential LVPECL ⁽⁴⁰⁾ ,	HCSL, and LVDS
Input frequency from REFCLK input pins	_	27		710	MHz
Rise time	Measure at ±60 mV of differential signal ⁽⁴¹⁾			400	ps
Fall time	Measure at ±60 mV of differential signal ⁽⁴¹⁾			400	ps
Duty cycle	—	45		55	%
Peak-to-peak differential input voltage	—	200		300 ⁽⁴²⁾ /2000	mV
Spread-spectrum modulating clock frequency	PCI Express (PCIe)	30		33	kHz
Spread-spectrum downspread	PCIe		0 to -0.5%		—
On-chip termination resistors	_		100		Ω
V _{ICM} (AC coupled)	—	_	1.2	—	V
V _{ICM} (DC coupled)	HCSL I/O standard for the PCIe reference clock	250		550	mV



⁽⁴⁰⁾ Differential LVPECL signal levels must comply to the minimum and maximum peak-to-peak differential input voltage specified in this table.

REFCLK performance requires to meet transmitter REFCLK phase noise specification. (41)

⁽⁴²⁾ The maximum peak-to peak differential input voltage of 300 mV is allowed for DC coupled link.

Typical TX V_{OD} Setting for Arria V Transceiver Channels with termination of 100 Ω

Table 1-32: Typical TX Vor	Setting for Arria V Transceive	r Channels with termination of 100 Ω
	, setting to suma t manseerre	

Symbol	V _{OD} Setting ⁽⁵⁸⁾	V _{OD} Value (mV)	V _{OD} Setting ⁽⁵⁸⁾	V _{OD} Value (mV)
	6 ⁽⁵⁹⁾	120	34	680
	7 ⁽⁵⁹⁾	140	35	700
	8(59)	160	36	720
	9	180	37	740
	10	200	38	760
	11	220	39	780
	12	240	40	800
	13	260	41	820
	14	280	42	840
V _{OD} differential peak-to-peak typical	15	300	43	860
-) F	16	320	44	880
	17	340	45	900
	18	360	46	920
	19	380	47	940
	20	400	48	960
	21	420	49	980
	22	440	50	1000
	23	460	51	1020
	24	480	52	1040

⁽⁵⁸⁾ Convert these values to their binary equivalent form if you are using the dynamic reconfiguration mode for PMA analog controls.

⁽⁵⁹⁾ Only valid for data rates \leq 5 Gbps.



Memory Output Clock Jitter Specifications

Table 1-45: Memory Output Clock Jitter Specifications for Arria V Devices

The memory output clock jitter measurements are for 200 consecutive clock cycles, as specified in the JEDEC DDR2/DDR3 SDRAM standard. The memory output clock jitter is applicable when an input jitter of 30 ps (p-p) is applied with bit error rate (BER) 10^{-12} , equivalent to 14 sigma. Altera recommends using the UniPHY intellectual property (IP) with PHYCLK connections for better jitter performance.

Parameter	Clock Network	Symbol	-I3,	-C4	–15,	-C5	-(6	Unit
Parameter		Symbol	Min	Max	Min	Max	Min	Max	Ont
Clock period jitter	PHYCLK	t _{JIT(per)}	-41	41	-50	50	-55	55	ps
Cycle-to-cycle period jitter	PHYCLK	t _{JIT(cc)}	6	3	9	0	9	4	ps

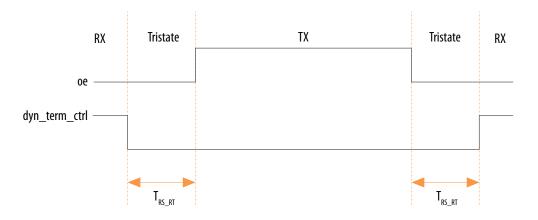
OCT Calibration Block Specifications

Table 1-46: OCT Calibration Block Specifications for Arria V Devices

Symbol	Description	Min	Тур	Max	Unit
OCTUSRCLK	Clock required by OCT calibration blocks			20	MHz
T _{OCTCAL}	Number of octus RCLK clock cycles required for R_S OCT/ R_T OCT calibration		1000		Cycles
T _{OCTSHIFT}	Number of octusrclk clock cycles required for oct code to shift out		32		Cycles
T _{RS_RT}	Time required between the dyn_term_ctrl and oe signal transitions in a bidirectional I/O buffer to dynamically switch between R_S OCT and R_T OCT	_	2.5	_	ns



Figure 1-7: Timing Diagram for oe and dyn_term_ctrl Signals



Duty Cycle Distortion (DCD) Specifications

Table 1-47: Worst-Case DCD on Arria V I/O Pins

The output DCD cycle only applies to the I/O buffer. It does not cover the system DCD.

Symbol	–I3,	-C4	-C5, -I5		-C6		Unit
	Min	Мах	Min	Мах	Min	Мах	Ont
Output Duty Cycle	45	55	45	55	45	55	%

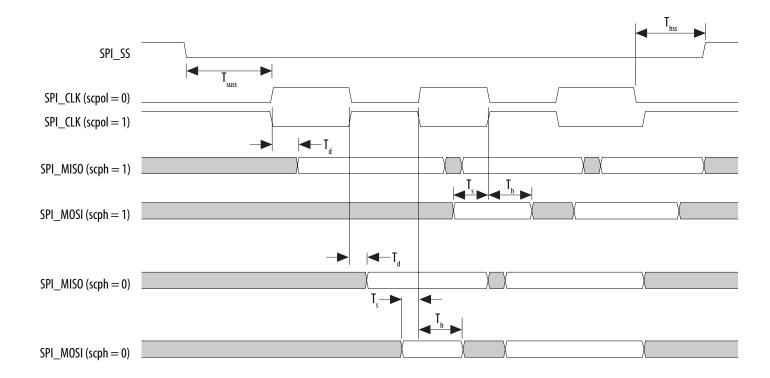
HPS Specifications

This section provides HPS specifications and timing for Arria V devices.

For HPS reset, the minimum reset pulse widths for the HPS cold and warm reset signals (HPS_nRST and HPS_nPOR) are six clock cycles of HPS_CLK1.



Figure 1-10: SPI Slave Timing Diagram



Related Information

SPI Controller, Arria V Hard Processor System Technical Reference Manual

Provides more information about rx_sample_delay.

SD/MMC Timing Characteristics

Table 1-54: Secure Digital (SD)/MultiMediaCard (MMC) Timing Requirements for Arria V Devices

After power up or cold reset, the Boot ROM uses drvsel = 3 and smplsel = 0 to execute the code. At the same time, the SD/MMC controller enters the Identification Phase followed by the Data Phase. During this time, the value of interface output clock SDMMC_CLK_OUT changes from a maximum of 400 kHz (Identification Phase) up to a maximum of 12.5 MHz (Data Phase), depending on the internal reference clock SDMMC_CLK and the CSEL setting. The value of SDMMC_CLK is based on the external oscillator frequency and has a maximum value of 50 MHz.



After the Boot ROM code exits and control is passed to the preloader, software can adjust the value of drvsel and smplsel via the system manager. drvsel can be set from 1 to 7 and smplsel can be set from 0 to 7. While the preloader is executing, the values for SDMMC_CLK and SDMMC_CLK_OUT increase to a maximum of 200 MHz and 50 MHz respectively.

The SD/MMC interface calibration support will be available in a future release of the preloader through the SoC EDS software update.

Symbol	Description	Min	Мах	Unit
	SDMMC_CLK clock period (Identification mode)	20	_	ns
T _{sdmmc_clk} (internal reference clock)	SDMMC_CLK clock period (Default speed mode)	5	_	ns
	SDMMC_CLK clock period (High speed mode)	5	_	ns
	SDMMC_CLK_OUT clock period (Identification mode)	2500	_	ns
T _{sdmmc_clk_out} (interface output clock)	SDMMC_CLK_OUT clock period (Default speed mode)	40	_	ns
	SDMMC_CLK_OUT clock period (High speed mode)	20	_	ns
T _{dutycycle}	SDMMC_CLK_OUT duty cycle	45	55	%
T _d	SDMMC_CMD/SDMMC_D output delay	$\frac{(T_{sdmmc_clk} \times drvsel)/2}{-1.23}$	$\begin{array}{c} (\mathrm{T}_{sdmmc_clk} \times \texttt{drvsel})/2 \\ + 1.69^{\ (87)} \end{array}$	ns
T _{su}	Input setup time	$1.05 - (T_{sdmmc_clk} \times smplsel)/2^{(88)}$		ns
T _h	Input hold time	$\frac{(T_{sdmmc_clk} \times \texttt{smplsel})}{2^{(88)}}$	—	ns



⁽⁸⁷⁾ drvsel is the drive clock phase shift select value.

⁽⁸⁸⁾ smplsel is the sample clock phase shift select value.

Table 1-57: RGMII RX Timing Requirements for Arria V Devices

Symbol	Description	Min	Тур	Unit
T _{clk} (1000Base-T)	RX_CLK clock period		8	ns
T _{clk} (100Base-T)	RX_CLK clock period		40	ns
T _{clk} (10Base-T)	RX_CLK clock period		400	ns
T _{su}	RX_D/RX_CTL setup time	1		ns
T _h	RX_D/RX_CTL hold time	1	—	ns

Figure 1-14: RGMII RX Timing Diagram

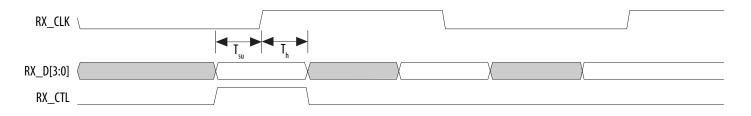


Table 1-58: Management Data Input/Output (MDIO) Timing Requirements for Arria V Devices

Symbol	Description	Min	Тур	Мах	Unit
T _{clk}	MDC clock period	_	400	_	ns
T _d	MDC to MDIO output data delay	10		20	ns
T _s	Setup time for MDIO data	10		_	ns
T _h	Hold time for MDIO data	0	_		ns



Symbol	Description	Min	Мах	Unit
T _{dh} ⁽⁸⁹⁾	Data to write enable hold time	5	—	ns
T _{cea}	Chip enable to data access time		25	ns
T _{rea}	Read enable to data access time		16	ns
T _{rhz}	Read enable to data high impedance		100	ns
T _{rr}	Ready to read enable low	20		ns

Figure 1-17: NAND Command Latch Timing Diagram

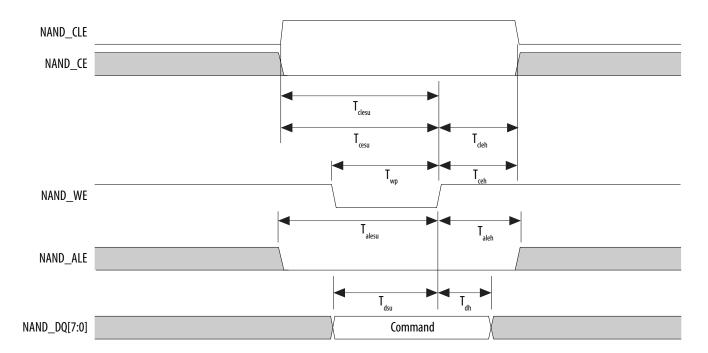
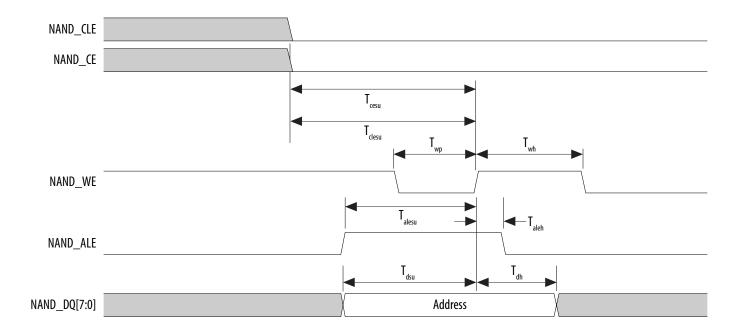




Figure 1-18: NAND Address Latch Timing Diagram







FPP Configuration Timing

DCLK-to-DATA[] Ratio (r) for FPP Configuration

Fast passive parallel (FPP) configuration requires a different DCLK-to-DATA[] ratio when you turn on encryption or the compression feature.

Depending on the DCLK-to-DATA[] ratio, the host must send a DCLK frequency that is r times the DATA[] rate in byte per second (Bps) or word per second (Wps). For example, in FPP $\times 16$ where the *r* is 2, the DCLK frequency must be 2 times the DATA[] rate in Wps.

Table 1-65: DCLK-to-DATA[] Ratio for Arria V Devices

Configuration Scheme	Encryption	Compression	DCLK-to-DATA[] Ratio (r)
	Off	Off	1
FPP (8-bit wide)	On	Off	1
rrr (o-on wide)	Off	On	2
	On	On	2
	Off	Off	1
FPP (16-bit wide)	On	Off	2
rrr (10-on wide)	Off	On	4
	On	On	4

FPP Configuration Timing when DCLK-to-DATA[] = 1

When you enable decompression or the design security feature, the DCLK-to-DATA[] ratio varies for FPP ×8 and FPP ×16. For the respective DCLKto-DATA[] ratio, refer to the DCLK-to-DATA[] Ratio for Arria V Devices table.

Table 1-66: FPP Timing Parameters When DCLK-to-DATA[] Ratio is 1 for Arria V Devices

Symbol	Parameter	Minimum	Maximum	Unit
t _{CF2CD}	nCONFIG low to CONF_DONE low	_	600	ns
t _{CF2ST0}	nconfig low to nstatus low	_	600	ns
t _{CFG}	nCONFIG low pulse width	2		μs

Arria V GX, GT, SX, and ST Device Datasheet

Altera Corporation



AV-51002 2017.02.10

The Quartus Prime Timing Analyzer provides a more accurate and precise I/O timing data based on the specifics of the design after you complete place-and-route.

Related Information

Arria V I/O Timing Spreadsheet

Provides the Arria V Excel-based I/O timing spreadsheet.

Programmable IOE Delay

	Minimum	Fast Model		Slow Model					- Unit	
	Settings	Offset ⁽¹¹³⁾	Industrial	Commercial	-C4	-C5	-C6	-13	-15	Onic
D1	32	0	0.508	0.517	0.870	1.063	1.063	0.872	1.057	ns
D3	8	0	1.763	1.795	2.999	3.496	3.571	3.031	3.643	ns
D4	32	0	0.508	0.518	0.869	1.063	1.063	1.063	1.057	ns
D5	32	0	0.508	0.517	0.870	1.063	1.063	0.872	1.057	ns

Table 1-76: I/O element (IOE) Programmable Delay for Arria V Devices

Programmable Output Buffer Delay

Table 1-77: Programmable Output Buffer Delay for Arria V Devices

This table lists the delay chain settings that control the rising and falling edge delays of the output buffer.

You can set the programmable output buffer delay in the Quartus Prime software by setting the **Output Buffer Delay Control** assignment to either positive, negative, or both edges, with the specific values stated here (in ps) for the **Output Buffer Delay** assignment.



⁽¹¹²⁾ You can set this value in the Quartus Prime software by selecting **D1**, **D3**, **D4**, and **D5** in the **Assignment Name** column of **Assignment Editor**.

⁽¹¹³⁾ Minimum offset does not include the intrinsic delay.

1-100 Document Revision History

Date	Version	Changes
November 2012	3.0	 Updated Table 2, Table 4, Table 9, Table 14, Table 16, Table 17, Table 20, Table 21, Table 25, Table 29, Table 36, Table 56, Table 57, and Table 60. Removed table: Transceiver Block Jitter Specifications for Arria V Devices. Added HPS information: Added "HPS Specifications" section. Added Table 38, Table 39, Table 40, Table 41, Table 42, Table 43, Table 44, Table 45, Table 46, Table 47, Table 48, Table 49, and Table 50. Added Figure 7, Figure 8, Figure 9, Figure 10, Figure 11, Figure 12, Figure 13, Figure 14, Figure 15, Figure 16, Figure 17, Figure 18, and Figure 19. Updated Table 3 and Table 5.
October 2012	2.4	 Updated Arria V GX V_{CCR_GXBL/R}, V_{CCT_GXBL/R}, and V_{CCL_GXBL/R} minimum and maximum values, and data rate in Table 4. Added receiver V_{ICM} (AC coupled) and V_{ICM} (DC coupled) values, and transmitter V_{OCM} (AC coupled) and V_{OCM} (DC coupled) values in Table 20 and Table 21.
August 2012	2.3	Updated the SERDES factor condition in Table 30.
July 2012	2.2	 Updated the maximum voltage for V_I (DC input voltage) in Table 1. Updated Table 20 to include the Arria V GX -I3 speed grade. Updated the minimum value of the fixedclk clock frequency in Table 20 and Table 21. Updated the SERDES factor condition in Table 30. Updated Table 50 to include the IOE programmable delay settings for the Arria V GX -I3 speed grade.
June 2012	2.1	Updated $V_{CCR_GXBL/R}$, $V_{CCT_GXBL/R}$, and $V_{CCL_GXBL/R}$ values in Table 4.



Bus Hold Specifications

Table 2-9: Bus Hold Parameters for Arria V GZ Devices

							Vc	CIO					
Parameter	Symbol	Conditions	1.2	2 V	1.5	5 V	1.8	8 V	2.5	5 V	3.() V	Unit
			Min	Max									
Low sustaining current	I _{SUSL}	V _{IN} > V _{IL} (maximum)	22.5		25.0	_	30.0	_	50.0		70.0		μΑ
High sustaining current	I _{SUSH}	V _{IN} < V _{IH} (minimum)	-22.5		-25.0		-30.0	_	-50.0		-70.0	_	μΑ
Low overdrive current	I _{ODL}	$\begin{array}{c} 0\mathrm{V} < \mathrm{V_{IN}} < \\ \mathrm{V_{CCIO}} \end{array}$		120	_	160		200		300	_	500	μA
High overdrive current	I _{ODH}	$0V < V_{IN} < V_{CCIO}$		-120		-160	_	-200		-300	_	-500	μΑ
Bus-hold trip point	V _{TRIP}	_	0.45	0.95	0.50	1.00	0.68	1.07	0.70	1.70	0.80	2.00	V

On-Chip Termination (OCT) Specifications

If you enable OCT calibration, calibration is automatically performed at power-up for I/Os connected to the calibration block.

Table 2-10: OCT Calibration Accuracy Specifications for Arria V GZ Devices

OCT calibration accuracy is valid at the time of calibration only.





Symbol	Description	Conditions	Calibration Ac	curacy	Unit
Symbol	Description	Conditions	C3, I3L	C4, I4	Onic
25-Ω R _S	Internal series termination with calibration (25- Ω setting)	V _{CCIO} = 3.0, 2.5, 1.8, 1.5, 1.2 V	±15	±15	%
50-Ω R _S	Internal series termination with calibration (50- Ω setting)	V _{CCIO} = 3.0, 2.5, 1.8, 1.5, 1.2 V	±15	±15	%
34- Ω and 40- Ω R _S	Internal series termination with calibration (34- Ω and 40- Ω setting)	V _{CCIO} = 1.5, 1.35, 1.25, 1.2 V	±15	±15	%
48-Ω, 60-Ω, 80-Ω, and 240-Ω R _S	Internal series termination with calibration (48- Ω , 60- Ω , 80- Ω , and 240- Ω setting)	$V_{CCIO} = 1.2 V$	±15	±15	%
50-Ω R _T	Internal parallel termination with calibration (50- Ω setting)	V _{CCIO} = 2.5, 1.8, 1.5, 1.2 V	-10 to +40	-10 to +40	%
20- Ω , 30- Ω , 40- Ω , 60- Ω , and 120- Ω $R_{\rm T}$	Internal parallel termination with calibration ($20-\Omega$, $30-\Omega$, $40-\Omega$, $60-\Omega$, and $120-\Omega$ setting)	V _{CCIO} = 1.5, 1.35, 1.25 V	-10 to +40	-10 to +40	%
60- Ω and 120- Ω $R_{\rm T}$	Internal parallel termination with calibration (60- Ω and 120- Ω setting)	$V_{CCIO} = 1.2$	-10 to +40	-10 to +40	%
25- $\Omega R_{S_left_shift}$	Internal left shift series termination with calibration (25- Ω R _{S_left_shift} setting)	V _{CCIO} = 3.0, 2.5, 1.8, 1.5, 1.2 V	±15	±15	%

Table 2-11: OCT Without Calibration Resistance Tolerance Specifications for Arria V GZ Devices

Symbol	Description	Conditions	Resistance Tolerance		Unit
Symbol	Description	Conditions	C3, I3L	C4, I4	Onit
- 8	Internal series termination without calibration (25- Ω setting)	V _{CCIO} = 3.0 and 2.5 V	±40	±40	%



I/O Standard		V _{CCIO} (V)			V _{REF} (V)			V _T	_T (V)
	Min	Тур	Max	Min	Тур	Max	Min	Тур	Мах
SSTL-135 Class I, II	1.283	1.35	1.418	$0.49 \times V_{CCIO}$	$0.5 imes V_{ m CCIO}$	$0.51 imes V_{ m CCIO}$	$0.49 \times V_{ m CCIO}$	$0.5 \times V_{CCIO}$	$0.51 \times V_{CCIO}$
SSTL-125 Class I, II	1.19	1.25	1.26	$0.49 \times V_{CCIO}$	$0.5 \times V_{ m CCIO}$	$0.51 \times V_{CCIO}$	$0.49 \times V_{ m CCIO}$	0.5 × VCCIO	$0.51 \times V_{CCIO}$
SSTL-12 Class I, II	1.14	1.20	1.26	$0.49 \times V_{CCIO}$	$0.5 imes V_{ m CCIO}$	$0.51 \times V_{ m CCIO}$	$0.49 \times V_{ m CCIO}$	0.5 × VCCIO	$0.51 \times V_{CCIO}$
HSTL-18 Class I, II	1.71	1.8	1.89	0.85	0.9	0.95	_	V _{CCIO} /2	_
HSTL-15 Class I, II	1.425	1.5	1.575	0.68	0.75	0.9		V _{CCIO} /2	_
HSTL-12 Class I, II	1.14	1.2	1.26	$0.47 \times V_{CCIO}$	$0.5 imes V_{ m CCIO}$	$0.53 \times V_{ m CCIO}$	_	V _{CCIO} /2	_
HSUL-12	1.14	1.2	1.3	$0.49 \times V_{CCIO}$	$0.5 imes V_{ m CCIO}$	0.51 × V _{CCIO}	_	—	_

Table 2-18: Single-Ended SSTL, HSTL, and HSUL I/O Standards Signal Specifications for Arria V GZ Devices

I/O Standard	V _{IL(D}	_{C)} (V)	V _{IH(DC}	_{_)} (V)	V _{IL(AC)} (V)	V _{IH(AC)} (V)	V _{OL} (V)	V _{OH} (V)	l _{ol} (mA)	l _{oh} (mA)
	Min	Max	Min	Max	Мах	Min	Max	Min	י _{סן} (וויה)	י _{oh} (יייי <i>ב</i> י)
SSTL-2 Class I	-0.3	V _{REF} – 0.15	V _{REF} + 0.15	V _{CCIO} + 0.3	V _{REF} – 0.31	V _{REF} + 0.31	V _{TT} – 0.608	V _{TT} + 0.608	8.1	-8.1
SSTL-2 Class II	-0.3	V _{REF} – 0.15	V _{REF} + 0.15	V _{CCIO} + 0.3	V _{REF} – 0.31	V _{REF} + 0.31	V _{TT} – 0.81	V _{TT} + 0.81	16.2	-16.2
SSTL-18 Class I	-0.3	V _{REF} – 0.125	V _{REF} + 0.125	V _{CCIO} + 0.3	V _{REF} – 0.25	V _{REF} + 0.25	V _{TT} - 0.603	V _{TT} + 0.603	6.7	-6.7



Symbol/Description	Conditions	Trans	ceiver Spee	d Grade 2	Transc	Unit		
Symbol/Description	Conditions	Min	Тур	Мах	Min	Тур	Max	Onit
	DC gain setting = 0		0	_	—	0	_	dB
	DC gain setting = 1	—	2	_		2	_	dB
Programmable DC gain	DC gain setting = 2		4	_		4		dB
	DC gain setting = 3	—	6	_	_	6	_	dB
	DC gain setting = 4	_	8	—	_	8	—	dB

Related Information

Arria V Device Overview

For more information about device ordering codes.

Transmitter

Table 2-25: Transmitter Specifications for Arria V GZ Devices

Speed grades shown refer to the PMA Speed Grade in the device ordering code. The maximum data rate could be restricted by the Core/PCS speed grade. Contact your Altera Sales Representative for the maximum data rate specifications in each speed grade combination offered. For more information about device ordering codes, refer to the *Arria V Device Overview*.

Symbol/Description	Conditions	Trans	ceiver Spee	d Grade 2	Transc	eiver Spee	ed Grade 3	Unit
Symbol/Description	Conditions	Min	Тур	Мах	Min	Тур	Мах	Onit
Supported I/O Standards	1.4-V and 1.5-V PCML							
Data rate (Standard PCS)	—	600	_	9900	600	_	8800	Mbps
Data rate (10G PCS)	_	600		12500	600	_	10312.5	Mbps



Typical VOD Settings

The tolerance is +/-20% for all VOD settings ex	cept for settings 2 and below	r.		
Symbol	V _{OD} Setting	V _{OD} Value (mV)	V _{OD} Setting	V _{OD} Value (mV)
	0 (166)	0	32	640
	1 ⁽¹⁶⁶⁾	20	33	660
	2(166)	40	34	680
	3(166)	60	35	700
	4 ⁽¹⁶⁶⁾	80	36	720
	5 ⁽¹⁶⁶⁾	100	37	740
	6	120	38	760
$ m V_{OD}$ differential peak to peak typical	7	140	39	780
	8	160	40	800
	9	180	41	820
	10	200	42	840
	11	220	43	860
	12	240	44	880
	13	260	45	900
	14	280	46	920

⁽¹⁶⁶⁾ If TX termination resistance = 100 Ω , this VOD setting is illegal.





Symbol	Conditions	C3, I3L		C4, I4			Unit	
		Min	Тур	Мах	Min	Тур	Max	Unit
True Differential I/O Standards - f _{HSDR} (data rate)	SERDES factor J = 3 to 10 (182), (183)	(184)	_	1250	(184)	_	1050	Mbps
	SERDES factor $J \ge 4$ LVDS TX with DPA (185), (186), (187), (188)	(184)		1600	(184)		1250	Mbps
	SERDES factor J = 2, uses DDR Registers	(184)		(189)	(184)		(189)	Mbps
	SERDES factor J = 1, uses SDR Register	(184)	_	(189)	(184)		(189)	Mbps
Emulated Differential I/O Standards with Three External Output Resistor Networks - f _{HSDR} (data rate) (190)	SERDES factor J = 4 to 10 $^{(191)}$	(184)		840	(184)		840	Mbps

⁽¹⁸²⁾ If the receiver with DPA enabled and transmitter are using shared PLLs, the minimum data rate is 150 Mbps.

- ⁽¹⁸⁵⁾ Arria V GZ RX LVDS will need DPA. For Arria V GZ TX LVDS, the receiver side component must have DPA.
- Requires package skew compensation with PCB trace length. (186)
- (187)Do not mix single-ended I/O buffer within LVDS I/O bank.
- Chip-to-chip communication only with a maximum load of 5 pF. (188)
- ⁽¹⁸⁹⁾ The maximum ideal data rate is the SERDES factor (J) x the PLL maximum output frequency (fOUT) provided you can close the design timing and the signal integrity simulation is clean.
- ⁽¹⁹⁰⁾ You must calculate the leftover timing margin in the receiver by performing link timing closure analysis. You must consider the board skew margin, transmitter channel-to-channel skew, and receiver sampling margin to determine leftover timing margin.
- ⁽¹⁹¹⁾ When using True LVDS RX channels for emulated LVDS TX channel, only serialization factors 1 and 2 are supported.



⁽¹⁸³⁾ The F_{MAX} specification is based on the fast clock used for serial data. The interface F_{MAX} is also dependent on the parallel clock domain which is design dependent and requires timing analysis.

⁽¹⁸⁴⁾ The minimum specification depends on the clock source (for example, the PLL and clock pin) and the clock routing resource (global, regional, or local) that you use. The I/O differential buffer and input register do not have a minimum toggle rate.

Symbol	Conditions	C3, I3L			C4, I4			Unit
		Min	Тур	Мах	Min	Тур	Max	
True Differential I/O Standards - f _{HSDRDPA} (data rate)	SERDES factor $J = 3$ to 10 (192), (193), (194), (195), (196), (197)	150	_	1250	150		1050	Mbps
	SERDES factor $J \ge 4$ LVDS RX with DPA (193), (195), (196), (197)	150		1600	150		1250	Mbps
	SERDES factor J = 2, uses DDR Registers	(198)		(199)	(198)		(199)	Mbps
	SERDES factor J = 1, uses SDR Register	(198)		(199)	(198)		(199)	Mbps
f _{HSDR} (data rate)	SERDES factor $J = 3$ to 10	(198)	—	(200)	(198)	_	(200)	Mbps
	SERDES factor J = 2, uses DDR Registers	(198)	—	(199)	(198)		(199)	Mbps
	SERDES factor J = 1, uses SDR Register	(198)	_	(199)	(198)		(199)	Mbps

 $^{(192)}$ The F_{MAX} specification is based on the fast clock used for serial data. The interface F_{MAX} is also dependent on the parallel clock domain which is design dependent and requires timing analysis.

⁽¹⁹³⁾ Arria V GZ RX LVDS will need DPA. For Arria V GZ TX LVDS, the receiver side component must have DPA.

⁽¹⁹⁴⁾ Arria V GZ LVDS serialization and de-serialization factor needs to be x4 and above.

⁽¹⁹⁵⁾ Requires package skew compensation with PCB trace length.

⁽¹⁹⁶⁾ Do not mix single-ended I/O buffer within LVDS I/O bank.

⁽¹⁹⁷⁾ Chip-to-chip communication only with a maximum load of 5 pF.

⁽¹⁹⁸⁾ The minimum specification depends on the clock source (for example, the PLL and clock pin) and the clock routing resource (global, regional, or local) that you use. The I/O differential buffer and input register do not have a minimum toggle rate.

⁽¹⁹⁹⁾ The maximum ideal data rate is the SERDES factor (J) x the PLL maximum output frequency (fOUT) provided you can close the design timing and the signal integrity simulation is clean.

⁽²⁰⁰⁾ You can estimate the achievable maximum data rate for non-DPA mode by performing link timing closure analysis. You must consider the board skew margin, transmitter delay margin, and receiver sampling margin to determine the maximum data rate supported.



JTAG Configuration Specifications

Symbol	Description	Min	Max	Unit
t _{JCP}	TCK clock period	30		ns
t _{JCP}	TCK clock period	167 (203)		ns
t _{JCH}	TCK clock high time	14		ns
t _{JCL}	TCK clock low time	14		ns
t _{JPSU (TDI)}	TDI JTAG port setup time	2	_	ns
t _{JPSU (TMS)}	TMS JTAG port setup time	3		ns
t _{JPH}	JTAG port hold time	5	_	ns
t _{JPCO}	JTAG port clock to output		11 (204)	ns
t_{JPZX}	JTAG port high impedance to valid output		14 (204)	ns
t _{JPXZ}	JTAG port valid output to high impedance	—	14 (204)	ns

Fast Passive Parallel (FPP) Configuration Timing

DCLK-to-DATA[] Ratio (r) for FPP Configuration

FPP configuration requires a different DCLK-to-DATA[] ratio when you turn on encryption or the compression feature.

Arria V GZ Device Datasheet

Altera Corporation



⁽²⁰³⁾ The minimum TCK clock period is 167 ns if VCCBAT is within the range 1.2V-1.5V when you perform the volatile key programming.

⁽²⁰⁴⁾ A 1-ns adder is required for each V_{CCIO} voltage step down from 3.0 V. For example, $t_{IPCO} = 12$ ns if V_{CCIO} of the TDO I/O bank = 2.5 V, or 13 ns if it equals 1.8 V.